

MP35005/W - MP3510/W

35A BRIDGE RECTIFIER

Features

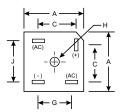
- Diffused Junction
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- Surge Overload Rating to 400A Peak
- Case to Terminal Isolation Voltage 1500V
- UL Listed: Recognized Component Index, File Number E95060

Mechanical Data

- Case: Molded Plastic with Heatsink Internally Mounted in the Bridge Encapsulation
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Symbols Marked on Case
- Mounting: Through Hole for #10 Screw
- Mounting Torque: 8.0 Inch-pounds Maximum
- MP Weight: 23 grams (approx.)
- MP-W Weight: 17 grams (approx.)
- Mounting Position: Any

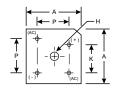


MP





MP-W



MP / MP-W								
Dim	Min	Max						
Α	28.40	28.70						
В	9.70	10.00						
С	15.70	16.70						
E	22.86	25.40						
G	13.50	14.50						
н	Hole for #10 screw							
	5.08Ø Nominal							
J	17.50	18.50						
K	10.90	11.90						
L	0.97∅	1.07Ø						
М	30.50	_						
Р	17.60	18.60						
All Dimensions in mm								

W Suffix Designates Wire Leads No Suffix Designates Faston Terminals

Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MP35 005/W	MP35 01/W	MP35 02/W	MP35 04/W	MP35 06/W	MP35 08/W	MP35 10/W	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T _C = 55°C	lo	35							Α
Non-Repetitive Peak Forward Surge Current, 8.3 ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				400				Α
Forward Voltage (per element) @ I _F = 17.5A		1.1							V
Peak Reverse Current					10 0.5				μA mA
I ² t Rating for Fusing (Note 1	l ² t				664				A ² s
Typical Junction Capacitance (Note 2	Cj				400				pF
Typical Thermal Resistance Junction to Case (Note 3	Rejc				3.8				K/W
Operating and Storage Temperature Range		-65 to +125						°C	

Notes:

- 1. Non-repetitive, for t > 1.0ms and t < 8.3ms.
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance junction to case per element mounted on heatsink.

